L Number	Hits	Search Text	DB	Time stamp
105	70	<pre>@ad<=20000731 and 'SGT' and (257/\$).ccls. and (438/\$).ccls.</pre>	USPAT; US-PGPUB;	2003/06/17 08:07
172	1037	(257/401).ccls. and @ad<=20000731	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/06/17 08:23
173	43	(438/284).ccls. and @ad<=20000731	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/06/17 08:23
-	6	(("5637884") or ("5811324")).PN.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/06/16 15:17
-	6	(("4979014") or ("5466621")).PN.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/05/07 14:38
_	382	(257/900).CCLS.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/05/07 14:39
_	378	((257/900).CCLS.) and @ad<=20000731	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/02/26 09:35
_	234007	(("257") or ("438")).CLAS.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2002/05/07 14:44
-	682	(((257/\$) or (438/\$)).CCLS.) and @ad<=20000731 and 'convex' with 'layer'	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/05/07
_	1	"5095347".PN.	IBM_TDB USPAT	2002/05/07
_	1	"5095347".PN.	USPAT	14:46 2002/05/07
_	1	"5120666".PN.	USPAT	14:46
_	1	"4774196".PN.	USPAT	14:46 2002/05/07 14:46
-	1	"5410172".PN.	USPAT	2002/05/07 14:47
_	1	"5420055".PN.	USPAT	2002/05/07
-	1	"5578513".PN.	USPAT	2002/05/07
_	1	"5580802".PN.	USPAT	2002/05/07
_	610	(((257/\$) or (438/\$)).CCLS.) and @ad<=20000731 and 'convex' with 'semiconductor'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/07

		~		
_	0	(((257/\$) or (438/\$)).CCLS.) and @ad<=20000731 and 'convex	USPAT; US-PGPUB;	2002/05/07
		semiconductor' and 'side-wall gate'	EPO; JPO; DERWENT; IBM TDB	
-	0	(((257/\$) or (438/\$)).CCLS.) and	USPĀT;	2002/05/07
		<pre>@ad<=20000731 and 'convex semiconductor' and 'side wall gate'</pre>	US-PGPUB; EPO; JPO;	14:53
		Semiconductor and side warr gate	DERWENT;	
			IBM_TDB	2000/05/05
-	1531	(((257/\$) or (438/\$)).CCLS.) and @ad<=20000731 and 'side wall gate'	USPAT; US-PGPUB;	2002/05/07
		Can't Booot, of and Sino wall gard	EPO; JPO;	
			DERWENT; IBM TDB	
-	40	((((257/\$) or (438/\$)).CCLS.) and	USPAT;	2002/05/07
		@ad<=20000731 and 'side wall gate') and	US-PGPUB;	15:09
		'convex'	EPO; JPO; DERWENT;	r .
			IBM_TDB	
-	238	(257/394).CCLS.	USPAT; US-PGPUB;	2002/05/07 15:12
			EPO; JPO;	13.12
			DERWENT; IBM TDB	
_	232	(257/394).ccls. and @ad<=20000731	USPAT;	2002/05/07
			US-PGPUB;	15:43
			EPO; JPO; DERWENT;	
	_		IBM_TDB	0000 (05 (07
_	1	"4979014".PN.	USPĀT	2002/05/07 15:30
-	1	"5463241".PN.	USPAT	2002/05/07
_	1	"5512770".PN.	USPAT	15:30
				15:31
-	156	(257/262).ccls. and @ad<=20000731	USPAT; US-PGPUB;	2002/05/07 15:56
			EPO; JPO;	
			DERWENT; IBM TDB	
-	17	'trench isolated transistor'	USPAT;	2002/05/07
			US-PGPUB; EPO; JPO;	15:57
			DERWENT;	
_	17	trench adj isolated adj transistor	IBM_TDB USPAT;	2002/05/07
		020.00. 44, 10014554 44, 014.02001	US-PGPUB;	16:18
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	1	"4449285".PN.	USPAT	2002/05/07 15:59
-	1	"4606011".PN.	USPAT	2002/05/07
_	1	"4670768".PN.	USPAT	15:59 2002/05/07
				15:59
-	1	"4449285".PN.	USPAT	2002/05/07 16:09
-	1	"4606011".PN.	USPAT	2002/05/07
_	1	"4670768".PN.	USPAT	16:09 2002/05/07
_	1	"4801988".PN.	USPAT	16:09 2002/05/07
	1	4001300 .FM.	USPAI	16:11
-	1	"4833516".PN.	USPAT	2002/05/07 16:11
-	1	"4910567".PN.	USPAT	2002/05/07
	1	"5013679".PN.	USPAT	16:11 2002/05/07
		3013079 .EM.	JOSEPH	16:12

-	1	"5013679".PN.	USPAT	2002/05/07 16:12
-	1	"5264716".PN.	USPAT	2002/05/07
-	1	"5289027".PN.	USPAT	2002/05/07
-	1	"5348905".PN.	USPAT	2002/05/07
-	1	"5360758".PN.	USPAT	2002/05/07
-	1	"5404037".PN.	USPAT	2002/05/07
-	1	"5567962".PN.	USPAT	2002/05/07
~	1	"5567962".PN.	USPAT	2002/05/07
-	1	"5567962".PN.	USPAT	2002/05/07
_	1	"5675164".PN.	USPAT	2002/05/07
-	1	"5909044".PN.	USPAT	2002/05/07
-	1	"5990510".PN.	USPAT	2002/05/07 16:15
-	1	"5994197".PN.	USPAT	2002/05/07 16:15
-	1	"5994729".PN.	USPAT	2002/05/07
-	1	"5998820".PN.	USPAT	2002/05/07
-	1	"5998821".PN.	USPAT	2002/05/07
-	1	"6008513".PN.	USPAT	2002/05/07
_	1	"6020609".PN.	USPAT	2002/05/07
-	1	"6025620".PN.	USPAT	2002/05/07 16:17
-	1	"6037210".PN.	USPAT	2002/05/07
-	2781	side adj wall adj gate	USPAT; US-PGPUB;	2002/05/07
			EPO; JPO; DERWENT;	10100
-	46	(side adj wall adj gate) and @ad<=20000731 and 'convex'	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/05/07 16:23
_	80	'side-wall' adj gates	IBM_TDB USPAT;	2002/05/07
			US-PGPUB; EPO; JPO; DERWENT; IBM TDB	16:27
-	77	('side-wall' adj gates) and @ad<=20000731	USPAT; US-PGPUB; EPO; JPO;	2002/05/07 16:43
-	24	'convex semiconductor layer'	DERWENT; IBM_TDB USPAT; US-PGPUB;	2002/05/08 07:58
_	24	'convex semiconductor layer'	EPO; JPO; DERWENT; IBM_TDB USPAT;	2002/05/08
			US-PGPUB; EPO; JPO; DERWENT; IBM TDB	08:13

-					_
1	-	1	"3278789".PN.	USPAT	
-	-	1	"3663857".PN.	USPAT	2002/05/08
- 1	-	1	"3735186".PN.	USPAT	2002/05/08
- 1	_	1	"4093562".PN.	USPAT	2002/05/08
- 1	-	1	"4325084".PN.	USPAT	2002/05/08
-	-	1	"5066883".PN.	USPAT	2002/05/08
1	_	1	"3805123".PN.	USPAT	2002/05/08
1	_	1	"5753966".PN.	USPAT	2002/05/08
1	_	1	"5753966".PN.	USPAT	2002/05/08
1	-	1	"5814532".PN.	USPAT	2002/05/08
- 1 "6037210".PN. USPAT 2002/05/08 08:31 - 1 "6026609".PN. USPAT 2002/05/08 08:31 - 1 "6020609".PN. USPAT 2002/05/08 08:31 - 1 "5998821".PN. USPAT 2002/05/08 08:31 - 155 'projection' near 'semiconductor substrate' USPAT; US-PGPUB; EPG; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPG; JPO; JPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPG; JPO; JPO; JPO; JPO;	-	1	"5972730".PN.	USPAT	2002/05/08
1	-	1	"6037210".PN.	USPAT	2002/05/08
- 1 "6020609".PN. 1 "5998821".PN. 1 "5998821".PN. 1 "5998821".PN. 1 "5998821".PN. 2 USPAT 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:31 2002/05/08 08:32 2002/05/08 09:54 2002/05/08 09:54 2002/05/08 09:54 2002/05/08 09:54 2002/05/08 09:54 2002/05/08 09:54 2002/05/08 09:54 2002/05/08 09:54 2002/05/08 20	_	1	"6025620".PN.	USPAT	2002/05/08
- 1 "5998821".PN. - 155 'projection' near 'semiconductor substrate' - 143 ('projection' near 'semiconductor substrate') and @ad<=20000731 - 143 ('projection' near 'semiconductor substrate') and @ad<=20000731 - 144 (257/192).ccls. and @ad<=20000731 - 145 ('projection' near 'semiconductor substrate') and @ad<=20000731 - 146 ('projection' near 'semiconductor uspart; IBM_TDB USPAT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; J	_	1	"6020609".PN.	USPAT	2002/05/08
- 155 'projection' near 'semiconductor substrate' - 143 ('projection' near 'semiconductor substrate') and @ad<=20000731	-	1	"5998821".PN.	USPAT	2002/05/08
Comparison Com	-	155			2002/05/08
Tame			substrate	EPO; JPO;	00.40
Substrate') and @ad<=20000731				IBM_TDB	
Top (257/192).ccls. and @ad<=20000731 Top (257/192).ccls. and @ad<=20000731 Top (257/192).ccls. and @ad<=20000731) Top (257/192).ccls. and @ad<=20000731) and (257/192).ccls. and @ad<=20000731) and (257/192).ccls. and @ad<=20000731) Top (257/386).ccls. and @ad<=20000731 Top (257/386).ccls. and @ad<=20000731 Top (257/387).ccls. and @ad<=20000731 Top (257/387).ccls. and @ad<=20000731 Top (257/387).ccls. and @ad<=20000731 Top (257/388).ccls. and @ad<=20000731	-	143			
- 799 (257/192).ccls. and @ad<=20000731 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB US-PGPUB; EPO; JPO; DERWENT; IBM TDB US-PGPUB; EPO; JPO; DERWENT; IBM					
US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	_	799	(257/192).ccls. and @ad<=20000731		
- 403 ((257/192).ccls. and @ad<=20000731) and (SPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO					08:22
- 403 ((257/192).ccls. and @ad<=20000731) and USPĀT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPĀT; US-PGPUB; EPO			·		
EPO; JPO; DERWENT; IBM_TDB USPAT; 2002/05/08 US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 2002/05/08 USPAT; 2002/05/08	-	403		USPAT;	
- 201 (257/386).ccls. and @ad<=20000731 IBM_TDB				EPO; JPO;	
US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 2002/05/08	1_	201	(257/386) ccls and @2d<=20000731	IBM_TDB	2002/05/08
DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 2002/05/08		201	(257, 500). CC15. and Gaux-20000731	US-PGPUB;	
- 244 (257/387).ccls. and @ad<=20000731 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 1002/05/08				DERWENT;	
EPO; JPO; DERWENT; IBM_TDB USPAT; 2002/05/08	-	244	(257/387).ccls. and @ad<=20000731	USPAT;	
IBM TDB				EPO; JPO;	20.20
		111	(257 (280) and and end-20000721	IBM_TDB	2002/05/08
EPO; JPO;	-	111	(25//300).CCIs. and @ad<=20000/31	US-PGPUB;	
DERWENT;				DERWENT;	
- 149 (257/389).ccls. and @ad<=20000731	-	149	(257/389).ccls. and @ad<=20000731	USPĀT;	
EPO; JPO;				EPO; JPO;	10.57
DERWENT; IBM_TDB					

-	259	(257/393).ccls. and @ad<=20000731	USPAT;	2002/05/08
			US-PGPUB;	10:39
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	315	(257/346).ccls. and @ad<=20000731	USPAT;	2002/05/08
			US-PGPUB;	10:43
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	93	(257/395).ccls. and @ad<=20000731	USPAT;	2002/05/08
		,==:,:==,:===	US-PGPUB;	10:47
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	67	(257/27).ccls. and @ad<=20000731	USPĀT;	2002/05/08
]	(201/21/100201 4114 6441 20000102	US-PGPUB;	10:49
			EPO; JPO;	100.5
			DERWENT;	
	1		IBM TDB	
	206	(257/69).ccls. and @ad<=20000731	USPAT;	2002/05/08
1 -	206	(257/69).CCIS. and Gaux-20000751	US-PGPUB;	10:54
	1		EPO; JPO;	10.03
	1		DERWENT;	
	1		IBM TDB	
		(420 (247) male and Gods-20000731	USPAT;	2002/05/08
-	39	(438/247).ccls. and @ad<=20000731	USPAT; US-PGPUB;	10:59
				10.39
			EPO; JPO;	
İ			DERWENT;	
i			IBM_TDB	2002 (05 (00
-	86	(438/159).ccls. and @ad<=20000731	USPAT;	2002/05/08
			US-PGPUB;	11:01
1			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	177	(438/155).ccls. and @ad<=20000731	USPAT;	2002/05/08
			US-PGPUB;	11:03
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	139	(257/348).ccls. and @ad<=20000731	USPAT;	2002/05/08
			US-PGPUB;	11:04
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	173	'surrounding gate transistor'	USPAT;	2003/02/25
			US-PGPUB;	16:01
			EPO; JPO;	
1			DERWENT;	
			IBM TDB	
_	1842	(257/296).ccls. and @ad<=20000731	USPĀT;	2002/10/02
	1012	1==:/===/:====	US-PGPUB;	10:31
			EPO; JPO;	
			DERWENT;	1
			IBM TDB	
l _	4811	((257/296) or (257/306) or (257/530) or	USPAT;	2003/02/26
1	4011	((257/354) or (438/238-239)).CCLS.	US-PGPUB;	09:44
	1	\23773347 OI \4307230~23977.00H3.	EPO; JPO;	
			DERWENT;	
			IBM TDB	
i	F 40	(/2E7/206) cala and 0nd/-20000727) and	USPAT;	2003/02/26
_	542	((257/296).ccls. and @ad<=20000731) and		09:42
1		'surrounding gate transistor' or 'SGT'	US-PGPUB;	07.42
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	2002/10/02
-	166	'surrounding gate transistor' and	USPAT;	2002/10/02
		@ad<=20000731	US-PGPUB;	10:41
			EPO; JPO;	
			DERWENT;	
	1		IBM TDB	

		, <u></u> -		
-	87	'gate electrode' with 'electric field effect'	USPAT; US-PGPUB;	2002/10/04 09:59
			EPO; JPO; DERWENT;	
	275		IBM_TDB	2002/10/04
-	275	'gate electrode applying'	USPAT; US-PGPUB;	2002/10/04 10:02
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	39	'gate electrode applying' with 'electric field'	USPAT; US-PGPUB;	2002/10/04
		electic field	EPO; JPO;	10.07
			DERWENT; IBM TDB	
_	2	'gate electrode applying' with	USPAT;	2002/10/04
		'electric field' with 'channel'	US-PGPUB;	10:10
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	87	'gate electrode applying' and 'electric field' and 'channel'	USPAT; US-PGPUB;	2002/10/04
		11014 and Chamier	EPO; JPO;	10.11
		·	DERWENT;	
_	196	'surrounding gate transistor'	IBM_TDB USPAT;	2003/02/26
			US-PGPUB;	09:30
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	1	"4979014".PN.	USPAT	2003/02/26
-	1	"5019878".PN.	USPAT	2003/02/26
-	1	"5089870".PN.	USPAT	2003/02/26
-	1	"5115289".PN.	USPAT	2003/02/26
-	1	"5163180".PN.	USPAT	2003/02/26 09:06
-	2	("5424227").PN.	USPAT; US-PGPUB;	2003/02/26
			EPO; JPO;	
			DERWENT; IBM TDB	
_	828	((257/192).CCLS.) and @ad<=20000731	USPAT;	2003/06/16
			US-PGPUB; EPO; JPO;	15:40
			DERWENT;	
		//257/106\ CGIS \ and Andz-20000721	IBM_TDB USPAT;	2003/02/26
-	46	((257/196).CCLS.) and @ad<=20000731	US-PGPUB;	09:35
			EPO; JPO;	
			DERWENT; IBM TDB	
-	577	((257/296).ccls. and @ad<=20000731) and	USPAT;	2003/02/26
		'surrounding gate transistor' or 'SGT'	US-PGPUB; EPO; JPO;	09:44
			DERWENT;	
_	23	((257/296).ccls. and @ad<=20000731) and	IBM_TDB USPAT;	2003/02/26
	2.5	'surrounding gate transistor'	US-PGPUB;	09:44
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	5205	((257/296) or (257/306) or (257/530) or	USPAT;	2003/02/26
		(257/354) or (438/238-239)).CCLS.	US-PGPUB; EPO; JPO;	09:49
			DERWENT;	
	L		IBM_TDB_	<u></u>

(-	4	(("5670810") or ("5414287")).PN.	USPAT;	2003/02/26
-	1	((3070010) OI (3414207)/.EN.	US-PGPUB;	11:04
				11:04
			EPO; JPO;	,
İ			DERWENT;	
			IBM_TDB	
-	2	"20020011612"	USPAT;	2003/06/16
			US-PGPUB;	15:17
			EPO; JPO;	1
			DERWENT;	
			IBM TDB	1
_	506	@ad<=20000731 and 'SGT'	USPAT:	2003/06/17
		044 200000	US-PGPUB;	08:06
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
İ	174	A-de-20000731 and surrounding adil sate	USPAT;	2003/06/16
-	174			
		adj1 transistor	US-PGPUB;	15:41
			EPO; JPO;	
			DERWENT;	1
			IBM TDB	